

# Superconducting Photocathodes

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# Cathode Options for SCRF Injector

- Use the niobium wall as a cathode

Simple, but low Nb QE limits current

J. Smedley, T. Rao, and Q. Zhao, J. Applied Physics **98**, 043111 2005

- Use an RF choke-joint to allow non-SC cathodes

Enables use of Cs<sub>2</sub>Te (and others)

D.Janssen et al., Nucl. Instr. And Meth. In Phys. Res. A445 (2000) 408-412.

- Coat Nb in cathode region with another superconductor, with better QE

# Comparison of Pb & Nb

## Lead

Type I Superconductor

Used in Ion Accelerators

Critical Magnetic Field\*: 80mT

Maximum Gradient\*: ~17MV/m

Critical Temperature: 7.9K

Photoelectric Work Function:  
3.95eV

## Niobium

Type II Superconductor

Many Accelerator Applications

Critical Magnetic Fields\*: 160mT,  
300mT

Maximum Gradient \*: >60MV/m

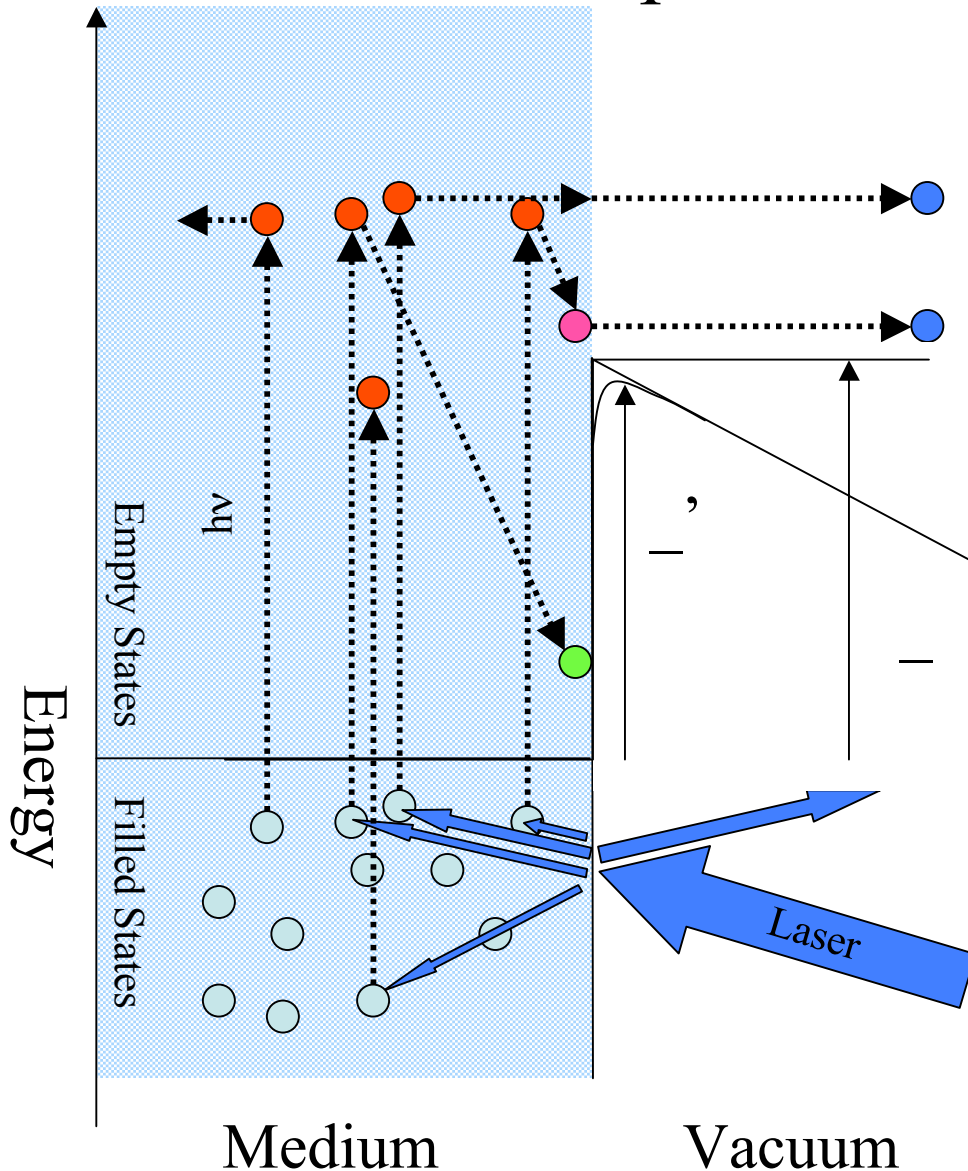
Critical Temperature: 9.2K

Photoelectric Work Function: 4.3eV

\* Values for 2K, 1.3 GHz

From: Basic Principles of RF Superconductivity and Superconducting Cavities, Peter Schmuser

# Three Step Model of Photoemission

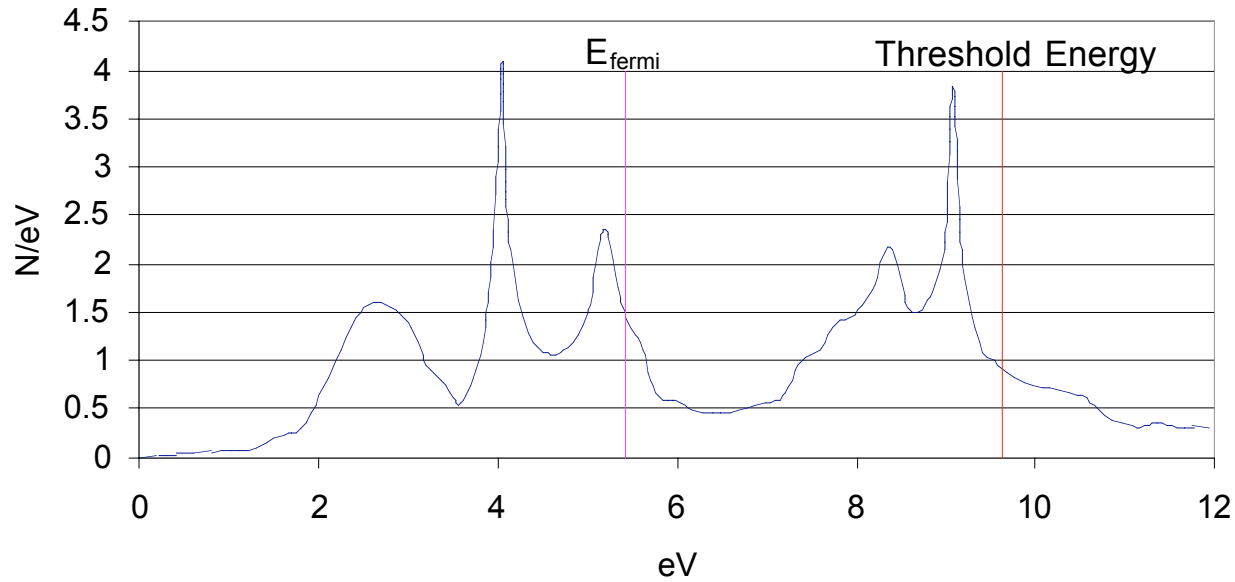


- 1) Excitation of  $e^-$  in metal
  - Reflection
  - Absorption of light
  - Energy distribution of excited  $e^-$
- 2) Transit to the Surface
  - $e^-e^-$  scattering
  - Direction of travel
- 3) Escape surface
  - Overcome Workfunction
  - Reduction of  $\Phi$  due to applied field (Schottky Effect)

Integrate product of probabilities over all electron energies capable of escape to obtain Quantum Efficiency

Nb Density of States

W.E. Pickett and P.B. Allen; Phy. Letters **48A**, 91 (1974)



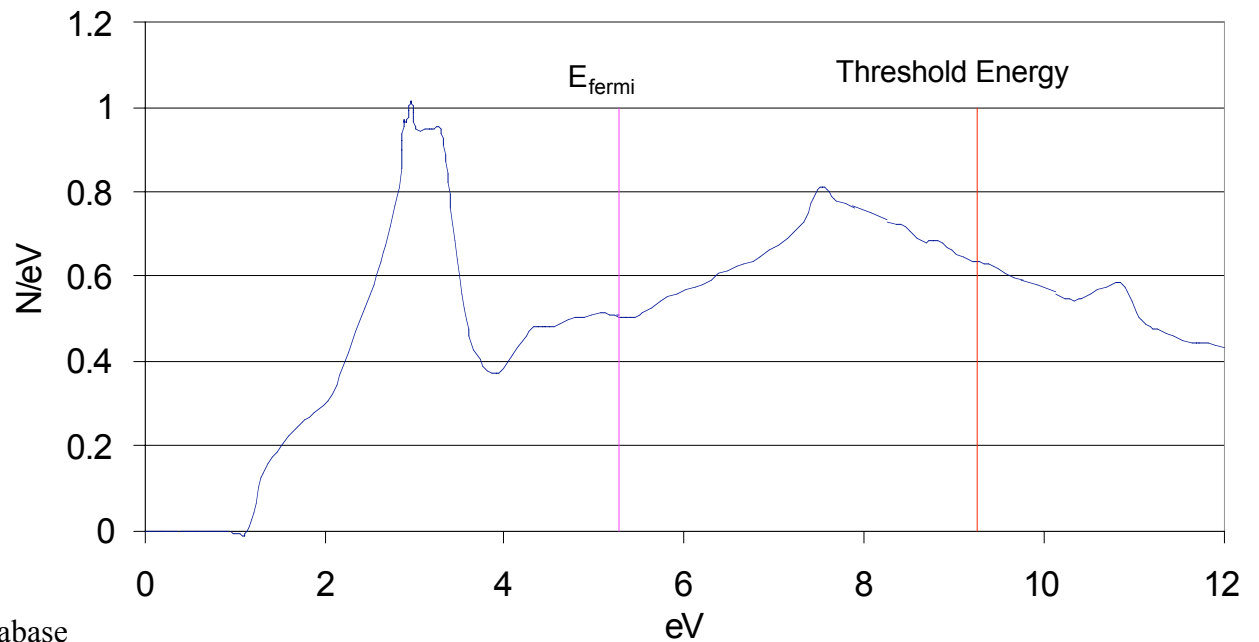
### Density of States for Nb

Large number of empty conduction band states promotes unproductive absorption

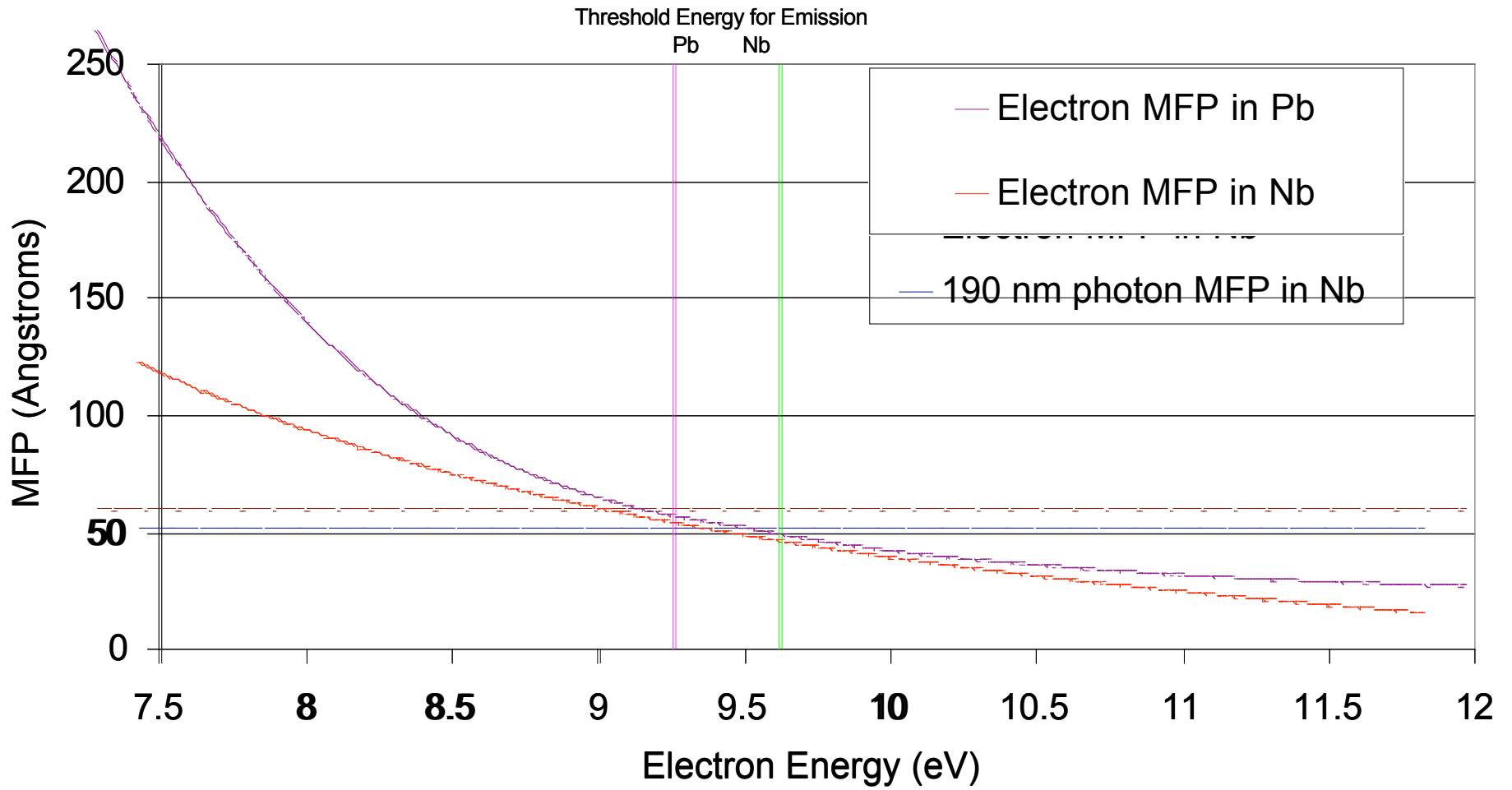
Lead Density of States

### Density of States for Lead

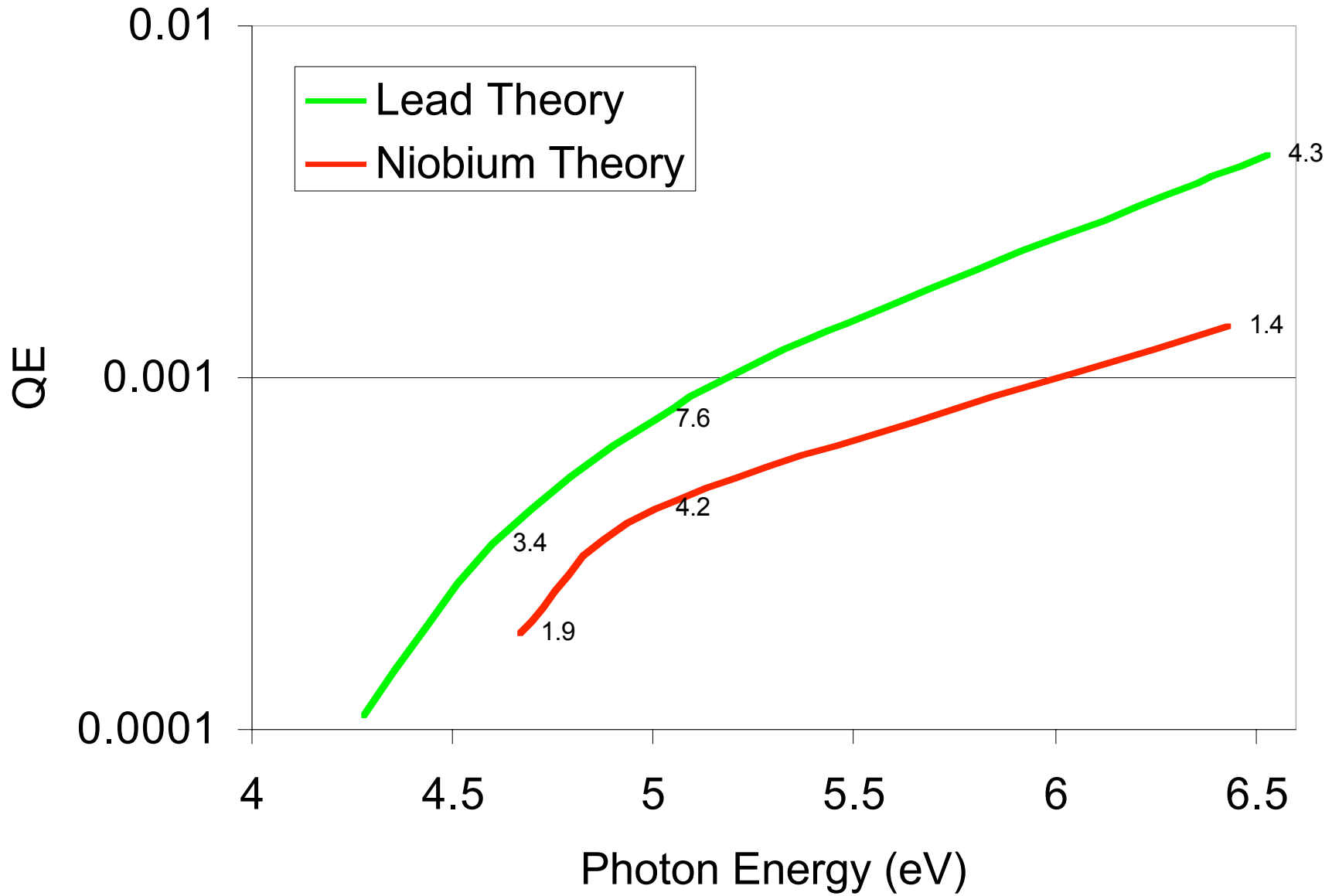
Lack of states below 1 eV limits unproductive absorption at higher photon energies



# Electron and Photon MFP in Lead and Niobium



# Predicted QE for Pb & Nb

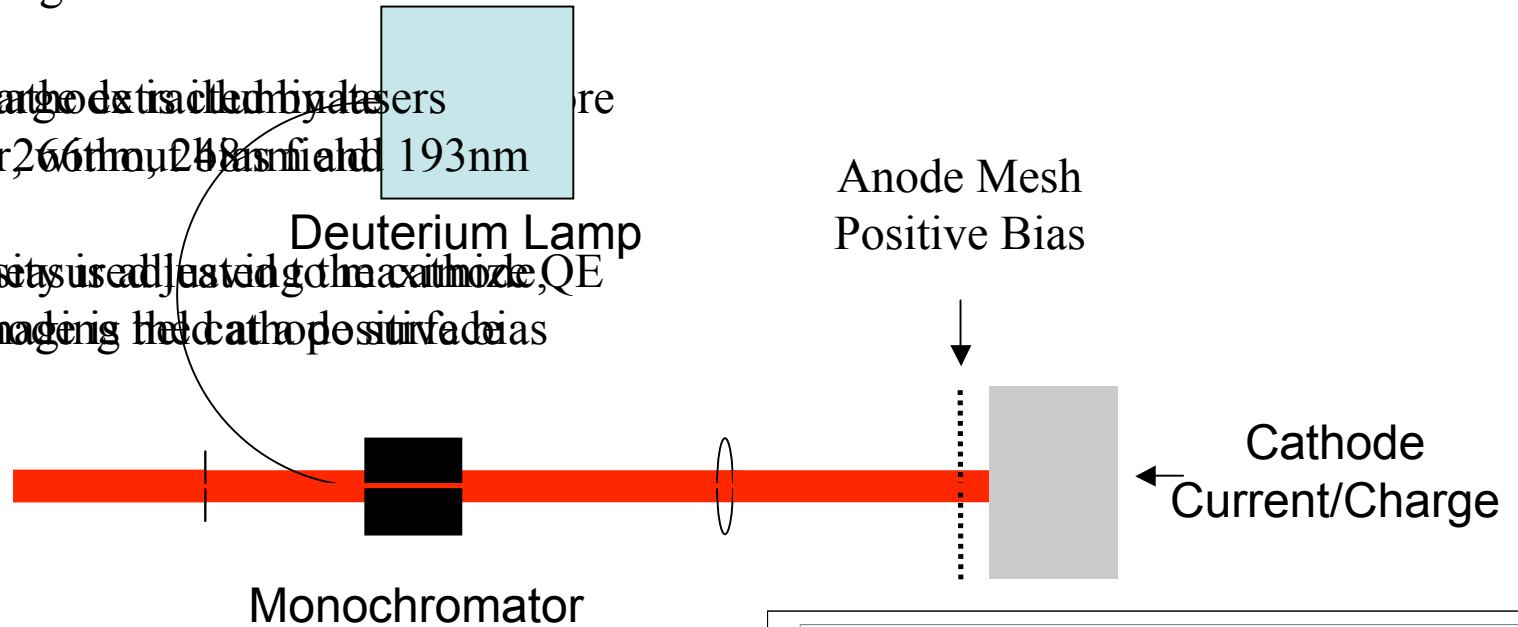


# QE Measurements

## Original System

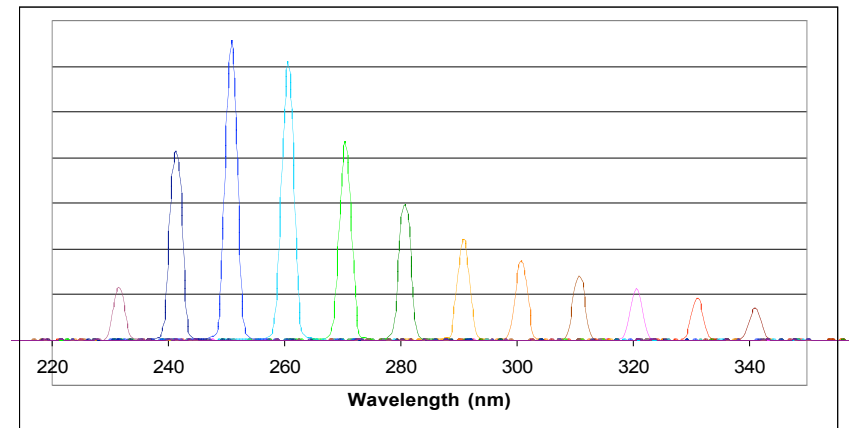
Surface charge detectors inhibit the use of intense laser sources  
 intensity set 2.66 through 2.88 mW/cm<sup>2</sup> 193nm

Energy density used just below the maximum QE  
 without damaging the cathode surface

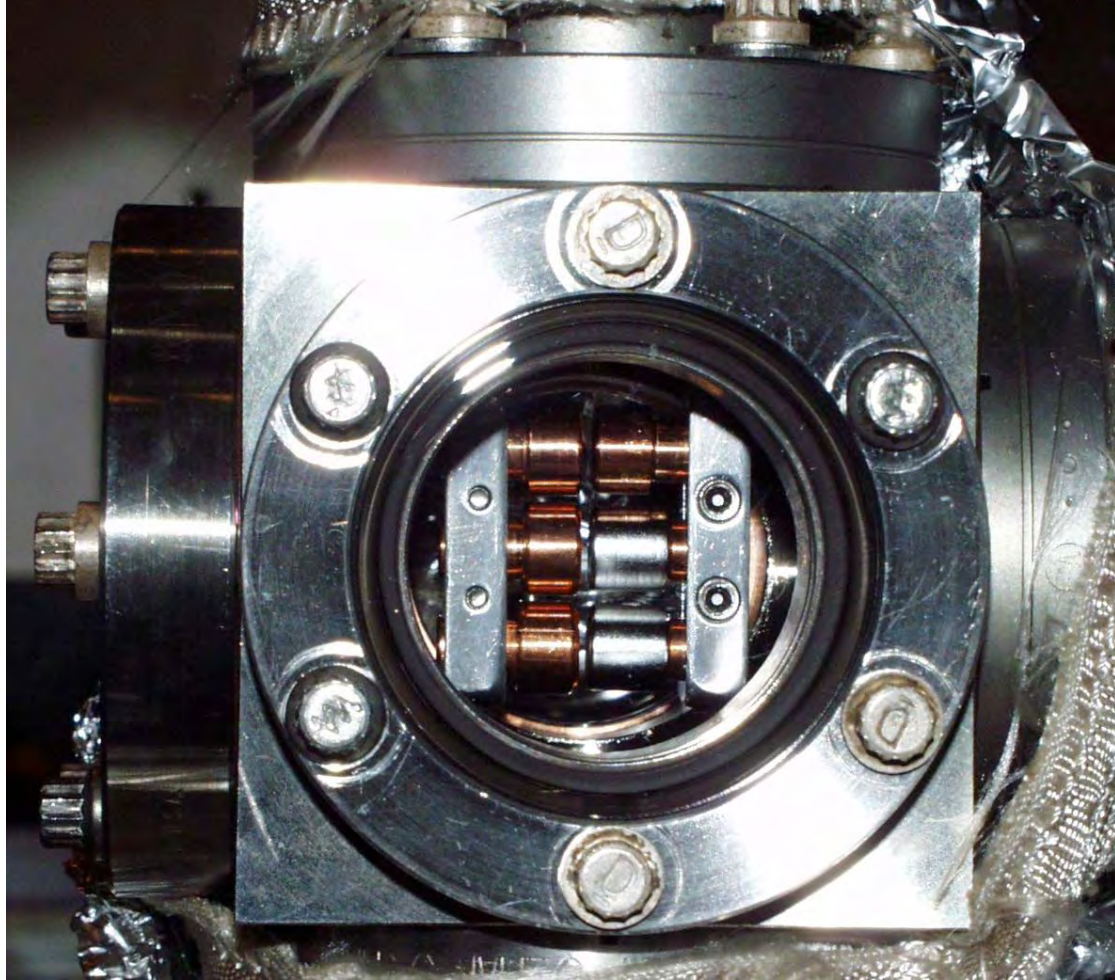


## Advantages of Lamp Source

- QE can be measured at any wavelength
- Material workfunction can be established
- Measurement source does not affect QE





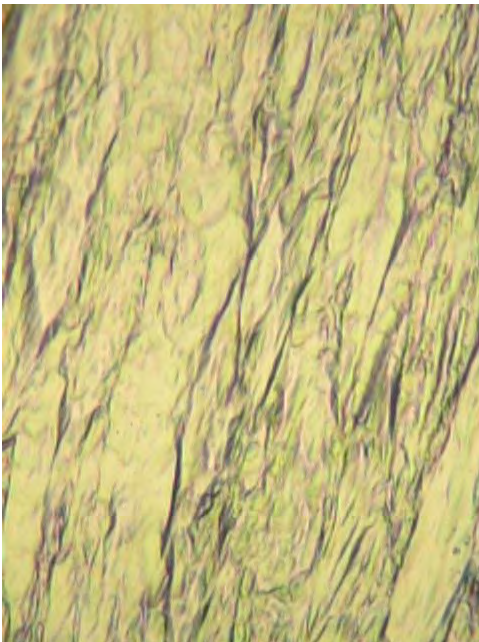


# Cathode Preparation - Niobium

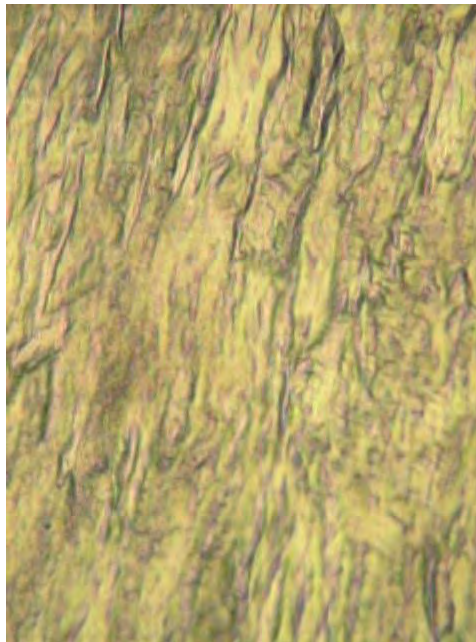
- Amorphous, RRR 250 Nb Cathodes
- Three surface preparations:
  - Mechanical polish (with diamond slurry)
  - Electropolishing
  - Buffered chemical polish
- In situ laser cleaning
  - Nd:YAG 4<sup>th</sup> harmonic (266 nm), 12 ps pulse,  $\sim 0.2$  mJ/mm<sup>2</sup>
  - KrF Excimer (248 nm), 12 ns pulse,  $\sim 2$  mJ/mm<sup>2</sup>

# Nb Surface Finish

Buffered Chemical Polish

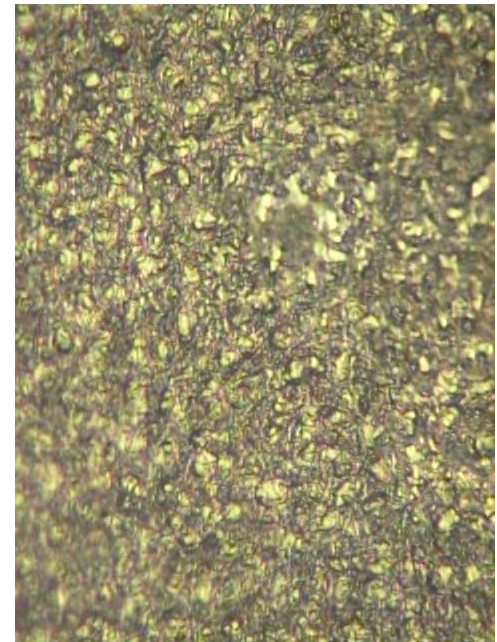


no laser cleaning



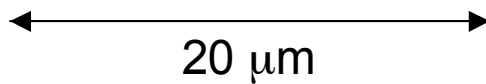
0.25 mJ/mm<sup>2</sup>

12 ps Nd:YAG (266 nm)

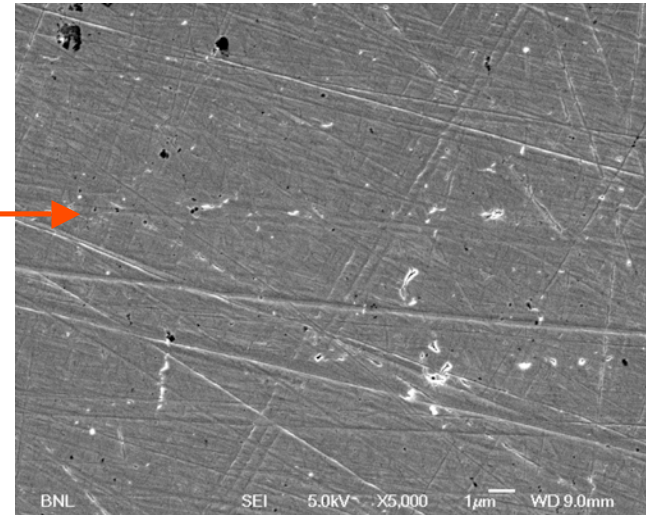
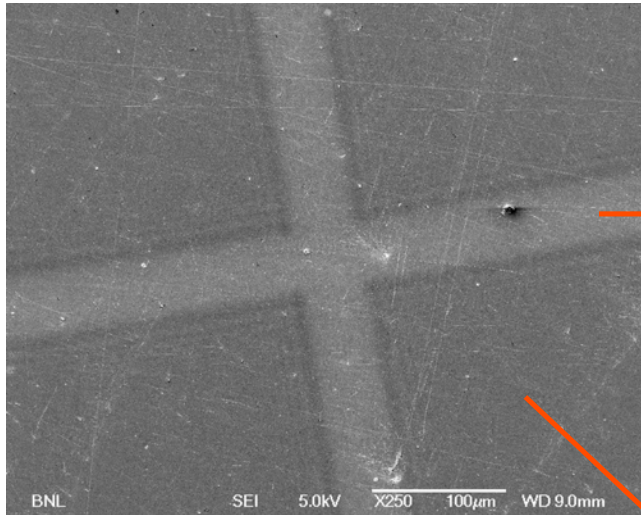


0.67 mJ/mm<sup>2</sup>

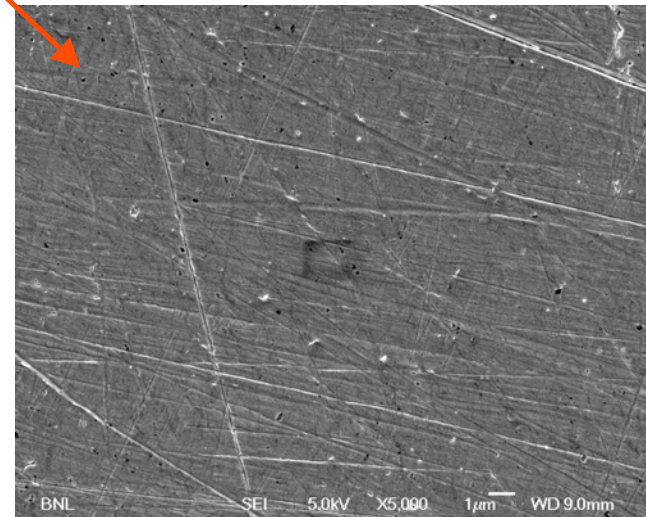
12 ps Nd:YAG (266nm)



# Nb Surface Finish

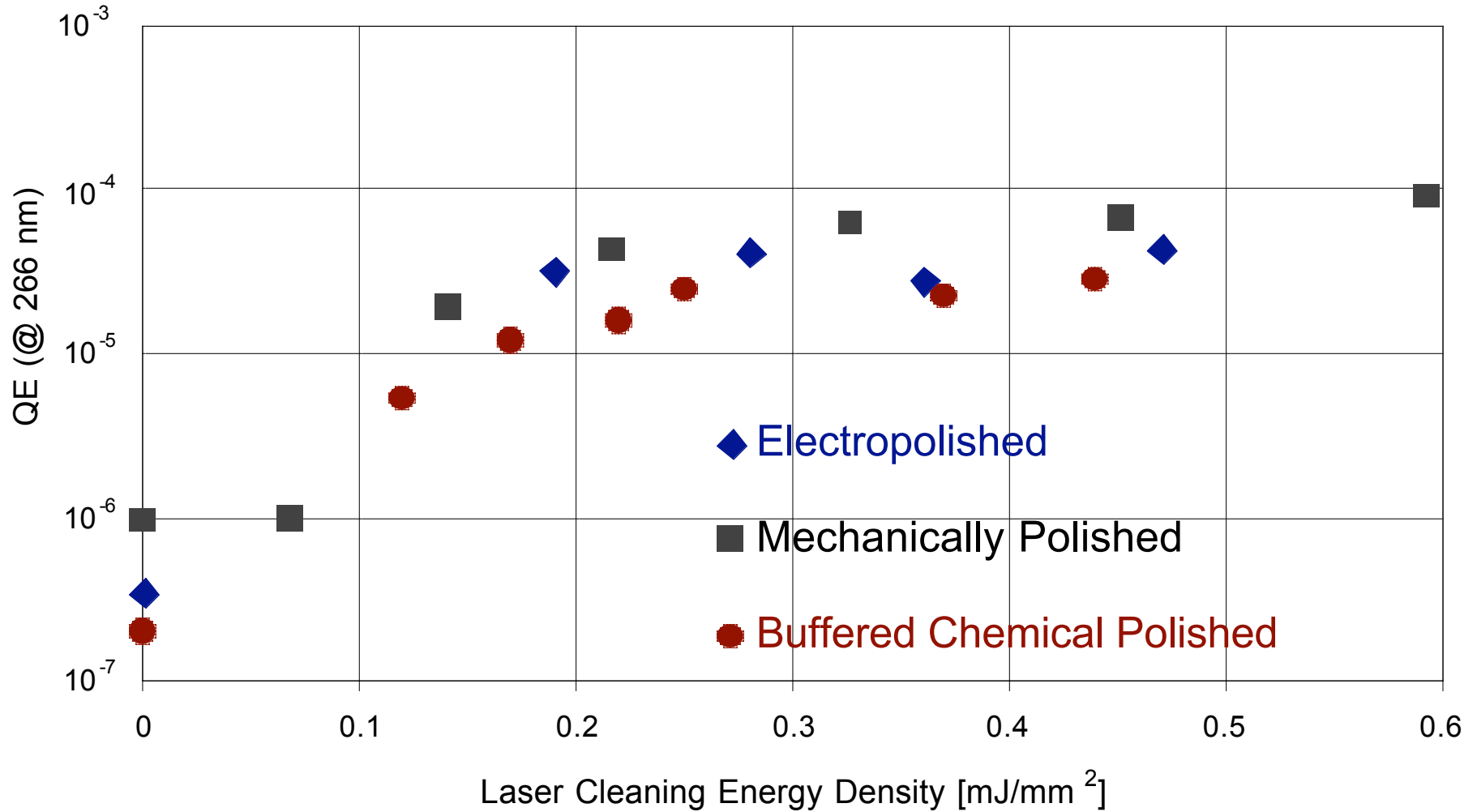


Mechanical Polish  
Laser Cleaned  
2.5 mJ/mm<sup>2</sup>  
12 ns KrF (248 nm)



# Laser Cleaning on Niobium

Cleaning with 12ps Nd: YAG (266 nm)

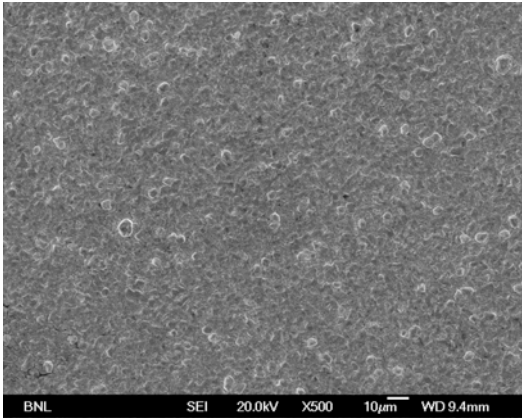


# Cathode Preparation - Lead

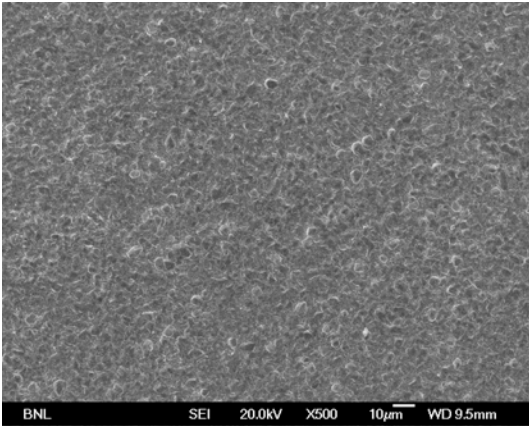
- Nb Cathodes used as substrate
- Four deposition methods:
  - Electroplating
  - Vacuum deposition (evaporation)
  - Sputtering
  - Vacuum Arc deposition
- Solid lead, mechanically polished
- In situ laser cleaning
  - KrF Excimer (248 nm), 12 ns pulse,  $\sim 0.2 \text{ mJ/mm}^2$

# Lead Surface Finish and Damage Threshold

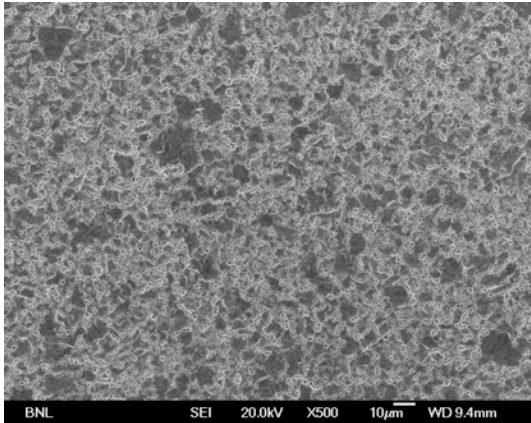
## Electroplated Lead



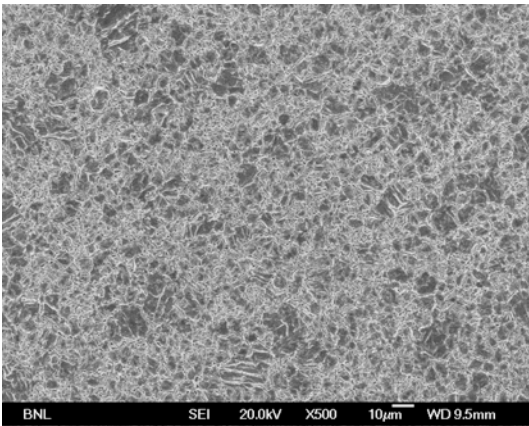
Prior to Laser Cleaning



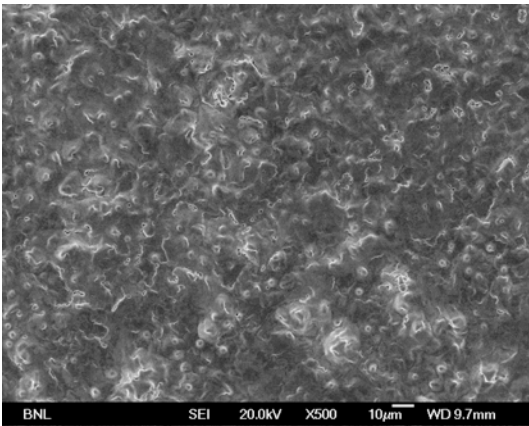
0.11 mJ/mm<sup>2</sup>



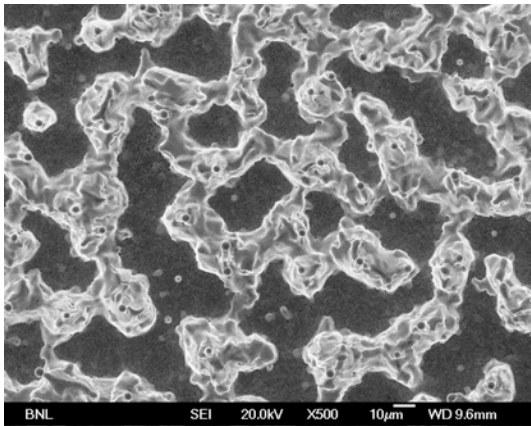
0.26 mJ/mm<sup>2</sup>



0.52 mJ/mm<sup>2</sup>



1.1 mJ/mm<sup>2</sup>



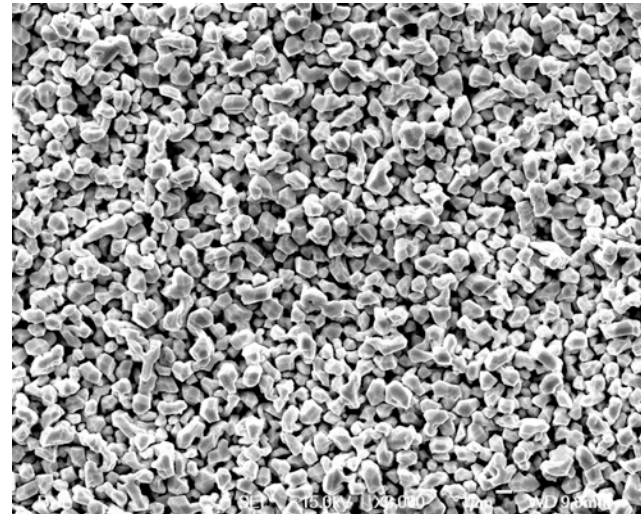
1.8 mJ/mm<sup>2</sup>

# Surface Uniformity

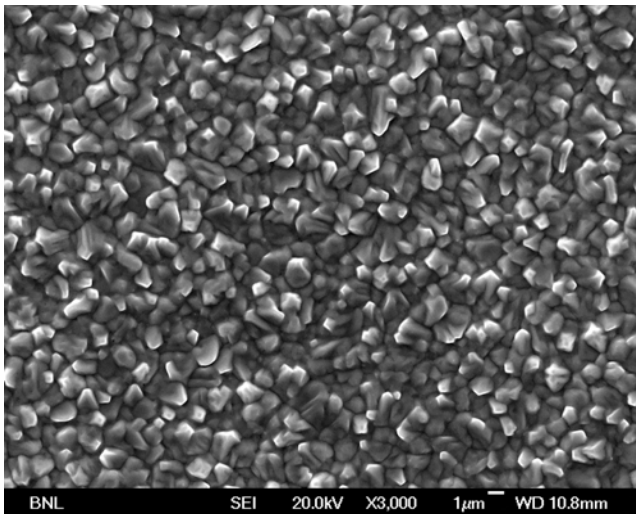
Arc  
Deposited



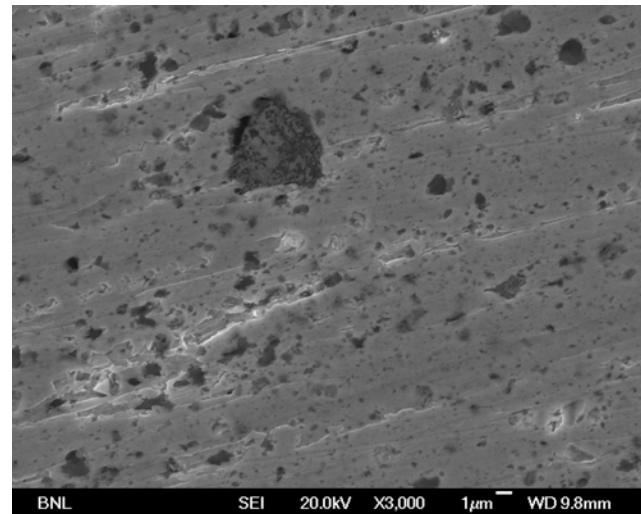
Sputtered



Vacuum  
Deposited



Solid



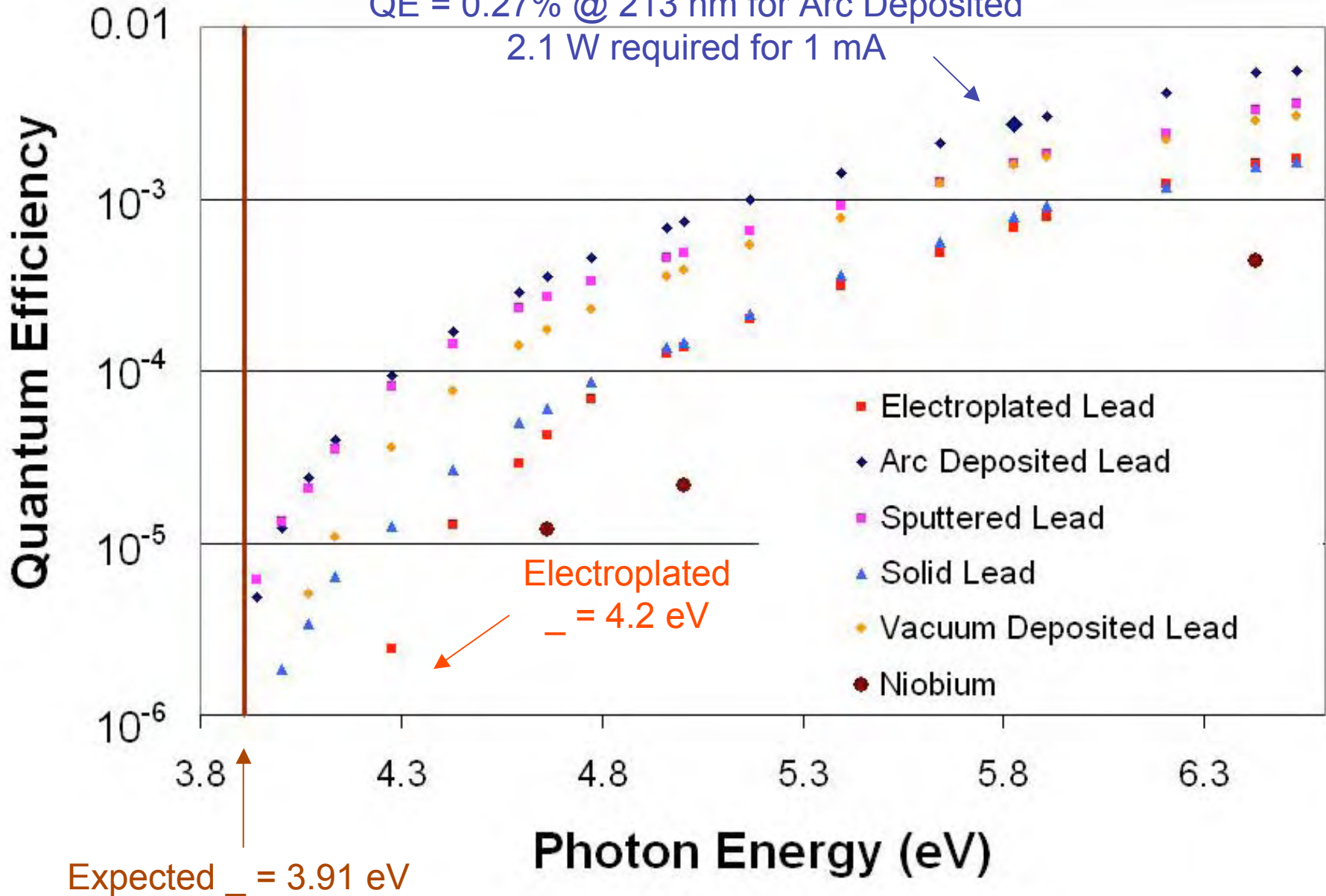
10 μm

All cathodes laser cleaned with 0.2 mJ/mm<sup>2</sup> of 248nm light

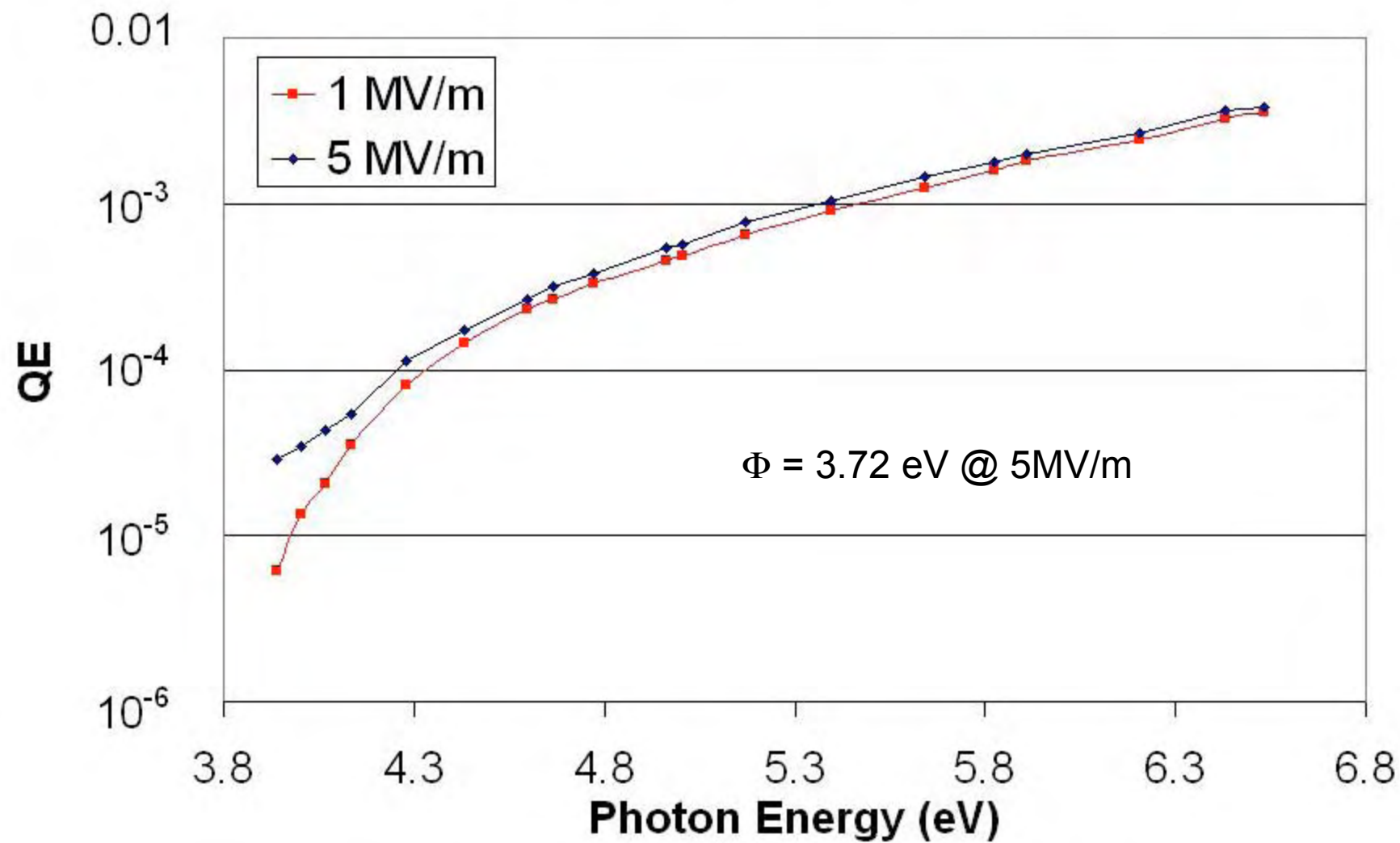


# Photoemission Results

QE = 0.27% @ 213 nm for Arc Deposited  
2.1 W required for 1 mA



## Sputtered Lead



# Cold Temperature QE

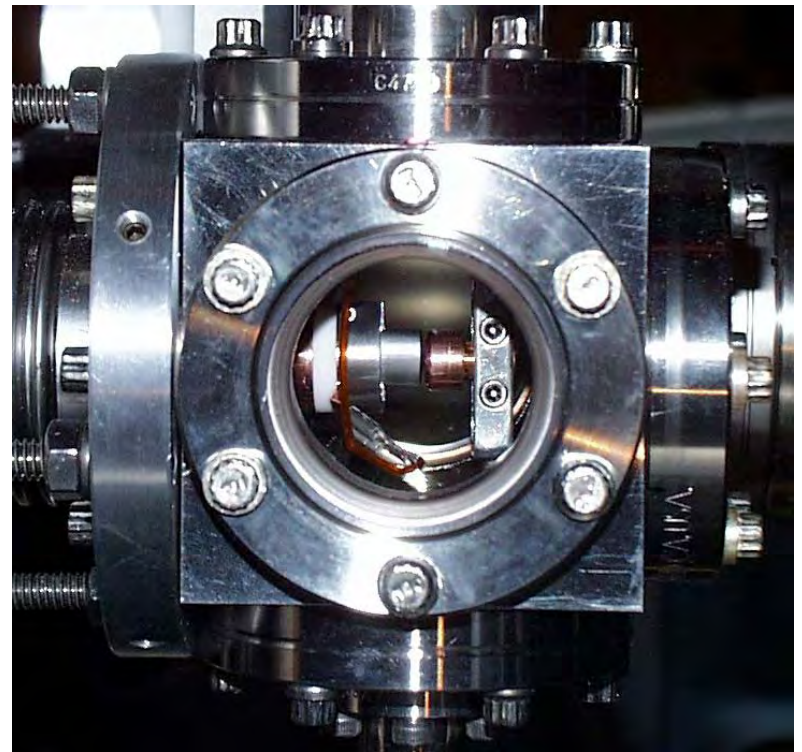
Previous measurements made at room temperature

How will lead behave at cryogenic temperatures?

To find out, we mounted the cathode on a LN<sub>2</sub> cooled vacuum cold finger, capable of reaching -170 C

Electroplated and Arc Deposited

Structurally, the lead coatings were unaffected by multiple warm/cold cycles

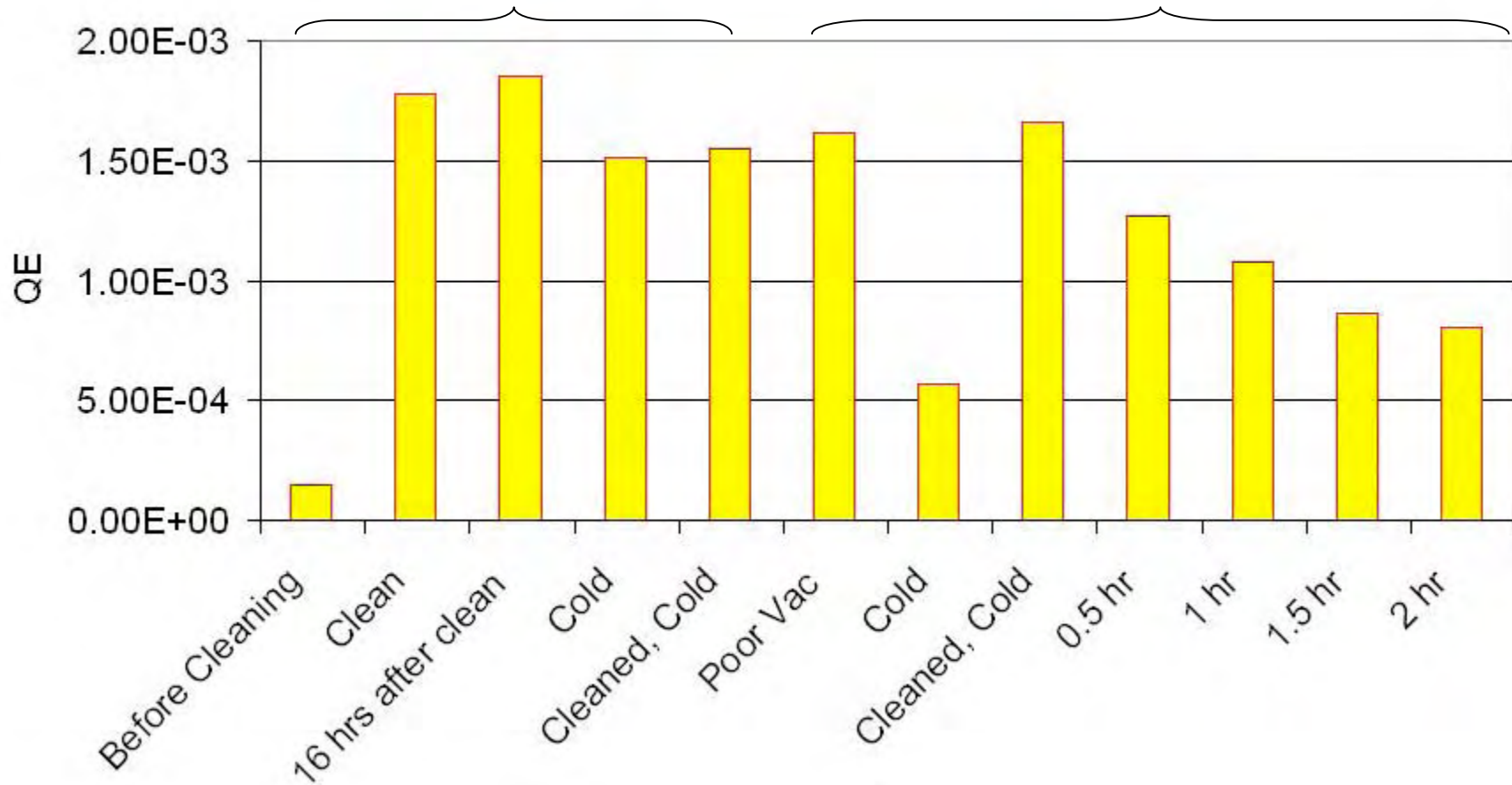


# Effect of Temperature and Vacuum on QE

Arc Deposited Cathode  
QE @ 200 nm

Vacuum (warm) = 8 nTorr  
Vacuum (-170C) = 6 nTorr

Vacuum (warm) = 1.3  $\mu$ Torr  
Vacuum (-170C) = 0.2  $\mu$ Torr



## Summary

- Niobium, although a great superconductor, is a relatively poor photocathode
- For moderate average currents, SC lead plating the cathode may be an attractive alternative to niobium
- $QE_{266\text{nm}}=0.035\%$ ,  $QE_{213\text{nm}}=0.27\%$ ,  $QE_{190\text{nm}}=0.55\%$
- Cold temperature operation is not a problem, as long as vacuum is good
- For higher average currents, an RF choke assembly can be used to accommodate high-QE cathodes